# **Robust Computation** through Percolation: Synthesizing Logic with Percolation in Nanoscale Lattices

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## **ABSTRACT**

This paper proposes a probabilistic framework for digital computation with lattices of nanoscale switches based on the mathematical phenomenon of percolation. With random connectivity, percolation gives rise to a sharp non-linearity in the probability of global connectivity as a function of the probability of local connectivity. This phenomenon is exploited to compute Boolean functions robustly in the presence of defects. It is shown that the margins, defined in terms of the steepness of the non-linearity, translate into the degree of defect tolerance. Achieving good margins entails a mapping problem. Given a target Boolean function, the problem is how to assign literals to regions of the lattice such that no diagonal paths of 1's exist in any assignment that evaluates to 0. Assignments with such paths result in poor error margins due to stray, random connections that can form across the diagonal. A necessary and sufficient condition is formulated for a mapping strategy that preserves good margins: the top-to-bottom and left-to-right connectivity functions across the lattice must be dual functions. Based on lattice duality, an efficient algorithm to perform the mapping is proposed. The algorithm optimizes the lattice area while meeting prescribed worst-case margins. Its effectiveness is demonstrated on benchmark circuits.

Keywords: Boolean Functions, Defect Tolerance, Duality, Logic Synthesis, Percolation

## INTRODUCTION

As current CMOS-based technology is approaching its anticipated limits, research is shifting to novel forms of nanoscale technologies including molecular-scale self-assembled systems (Whitesides & Grzybowski, 2002; Yan, Park, Finkelstein, Reif, & LaBean, 2003). Un-

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like conventional CMOS that can be patterned in complex ways with lithography, self-assembled systems generally consist of regular structures such as crossbar arrays (Ziegler & Stan, 2003; Eshaghian-Wilner, Flood, Khitun, Stoddart, & Wang, 2006). In particular, with self-assembly, nanoscale technologies are often characterized by high defect rates. A variety of techniques have been proposed for mitigating against defects (Huang, Tahoori, & Lombardi, 2004; Kuekes, Robinett, Seroussi, & Williams, 2005; Sun & Zhang, 2006; Hogg & Snider, 2007; Snider & Williams, 2007).

In prior work, we discussed strategies for implementing Boolean functions with lattices of four-terminal switches (Altun & Riedel, 2010, in press). We addressed the synthesis problem of how best to assign literals to switches in a lattice in order to implement a given target Boolean function, with the goal of minimizing the lattice size, measured in terms of the number of switches. We presented an efficient synthesis algorithm for this task. The algorithm has polynomial time complexity (significantly, it does not exhaustively enumerate paths). It produces lattices with a size that grows linearly with the number of products of the target Boolean function.

In this paper, we address the problem of implementing Boolean functions with lattices of four-terminal switches in the presence of defects. We assume that such defects occur probabilistically. Although not tied to any particular technology, our model could be applicable for emerging technologies such as nanowire crossbar arrays (Cui & Lieber, 2001) and magnetic switch-based structures (Khitun, Bao, & Wang, 2008).

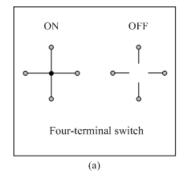
Our approach is predicated on the mathematical phenomenon of percolation. With random connectivity, percolation gives rise to a sharp non-linearity in the probability of global connectivity as a function of the probability of local connectivity. We exploit this phenomenon to compute Boolean functions robustly, within prescribed error margins.

The paper is organized as follows. In the next section, we present our circuit model, followed by our defect model. We then discuss the mathematics of percolation and how this phenomenon can be exploited for tolerating defects. We examine potential technologies that fit our model. We then present our main technical result: a method for assigning Boolean literals to sites in a switching lattice that optimizes the lattice area while meeting prescribed defect tolerances. We evaluate our method on benchmark circuits

#### **Circuit Model**

Our circuit model consists of regular twodimensional arrays of four-terminal switches. A four-terminal switch is shown in the top part of Figure 1. It has two states, ON and OFF, that are controlled by a Boolean literal. If the literal takes the value 1 then the four ends of the switch are mutually connected—the switch is ON. If the literal takes the value 0 then the four ends of the switch are mutually disconnected – the switch is OFF. A network of four-terminal switches is shown in Figure 1(b). The Boolean function for the network evaluates to 1 iff there is a closed path between the top and bottom plates of the lattice. It can be computed by taking the sum (OR) of the product (AND) of literals along each

Figure 1. (a) Four-terminal switch with its ON and OFF states, and (b) Four-terminal switching network implementing the Boolean function  $x_1x_2x_3 + x_1x_2x_3x_4 + x_2x_3x_4x_5 + x_4x_5x_6$ 



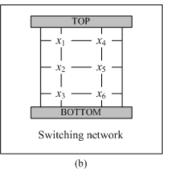
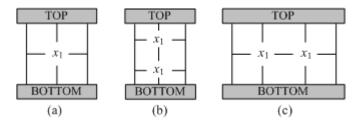


Figure 2. Switching networks



path. These paths are 
$$x_1 - x_2 - x_3$$
,  $x_1 - x_2 - x_5 - x_6$ ,  $x_4 - x_5 - x_2 - x_3$ , and  $x_4 - x_5 - x_6$ .

#### **Defects and Defect Tolerance**

We assume that defects cause switches to fail in one of two ways: they are ON when they are supposed to be OFF, i.e., the controlling literal is 0; or they are OFF when they are supposed to be ON, i.e., the controlling literal is 1. We assume that switches can fail in one of these two ways, or both. As we discuss in the next section, we allow for different defect rates in both directions, ON-to-OFF and OFF-to-ON. Crucially, we assume that all switches fail with *independent* probability.

Defective switches can ruin the Boolean computation performed by a network. Consider the networks shown in Figure 2. The network in Figure 2(a) consists of a single switch. The networks in Figure 2(b) and Figure 2(c) consist of a pair of switches in series and in parallel, respectively. All switches are controlled by the literal  $x_1$ . Obviously, in each of these networks, the top and bottom plates are connected when  $x_1 = 1$  and disconnected when  $x_1 = 0$ . Therefore they implement the function  $f = x_1$ .

Note that the three networks are not identical in their defect-tolerance capability. Suppose that exactly one switch in each network is defective when  $x_1 = 1$  and exactly one is defective when  $x_1 = 0$ . When  $x_1 = 1$ , the networks in Figure 2(a) and Figure 2(b) compute the wrong value of f = 0; however, the network in Figure 2(c) computes the correct value f = 1. Similarly, when  $x_1 = 0$ , the networks in Figure 2(a) and Figure 2(c) compute the wrong value of f = 1. However, the network in Figure 2(b)

computes the correct value of f=0. So the series and parallel networks in Figures 2(b) and 2(c) each tolerate up to one defective switch, but they tolerate different defect types. None of these networks tolerates defects for both cases  $x_1 = 1$  and  $x_1 = 0$ .

Now consider the network in Figure 3. Compared to the networks in Figure 2, it has more switches. We expect that it will be superior in terms of its defect tolerance, for both the cases  $x_1 = 1$  and  $x_1 = 0$ . But what is the relationship between the amount of redundancy and the defect tolerance that is achieved? As we discuss previously, the relationship is non-linear. The explanation hinges on percolation.

Throughout the rest of the paper, we will use a lattice representation. White and black sites represent OFF and ON switches, respectively. If  $x_1 = 1$ , each four-terminal switch is ideally ON and represented by a black site. If  $x_1 = 0$ , each four-terminal switch is ideally OFF and represented by a white site. Due to defects, not all switches will behave in this way. Defective switches are represented by white and black sites while the switch is supposed to be ON and OFF, respectively. This is illustrated in Figure 3. Note that in spite of defects, the network in Figure 3 computes correctly for both the cases  $x_1 = 0$  and  $x_1 = 1$ .

# **Percolation**

Percolation theory is a rich mathematical topic that forms the basis of explanations of physical phenomena such as diffusion and phase changes in materials. It tells us that in media with random local connectivity, there is a critical threshold for global connectivity: below the threshold,

ideal real DEFECTS TOP

ideal

Figure 3. Switching network with defects

the probability of global connectivity quickly drops to zero; above it, the probability quickly rises to one.

Broadbent and Hammersley described percolation with the following metaphorical model (Broadbent & Hammersley, 1957). Suppose that water is poured on top of a large porous rock. Will the water find its way through holes in the rock to reach the bottom? We can model the rock as a collection of small regions each of which is either a hole or not a hole. Suppose that each region is a hole with independent probability  $p_1$  and not a hole with probability  $1 - p_1$ . The theory tells us that if  $p_1$  is above a critical value  $p_{s}$ , the water will always reach the bottom; if  $p_{s}$ is below pc, the water will never reach the bottom. The transition in the probability of water reaching bottom as a function of increasing p1 is extremely abrupt. For an infinite size rock, it is a step function from 0 to 1 at  $p_a$ .

In two dimensions, percolation theory can be studied with a lattice, as shown in Figure 4(a). Here each site is black with probability  $p_1$  and white with probability  $1 - p_1$ . Let  $p_2$  be the probability that a connected path of black sites exists between the top and bottom plates. Figure 4(b) shows the relationship between  $p_1$ and  $p_{\gamma}$  for different square lattice sizes. Percolation theory tells us that with increasing lattice

size, the steepness of the curve increases. (In the limit, an infinite lattice produces a perfect step function.) Below the critical probability  $p_c$ ,  $p_2$  is approximately 0 and above it  $p_2$  is approximately 1.

Suppose that each site of a percolation lattice is a four-terminal switch controlled by the same literal  $x_1$ . Also suppose that each switch is independently defective with the same probability. Defective switches are represented by white and black sites while the switch is supposed to be ON and OFF, respectively. Let's analyze the cases  $x_1 = 0$  and  $x_1 = 1$ . If  $x_1 = 0$ then each site is black with the defect probability, and the defective black sites might cause an error by forming a path between the top and bottom plates. In this case,  $p_1$  and  $p_2$  described in the percolation model correspond to the defect probability and the probability of an error in top-to-bottom connectivity, respectively. If  $x_1 = 1$  then each site is white with the defect probability and the defective white sites might cause an error by destroying the connection between the top and bottom plates. In this case,  $p_1$  and  $p_2$  in the percolation model correspond to 1–(defect probability) and 1–(probability of an error in top-to-bottom connectivity), respectively. The relationship between  $p_1$ and  $p_{\gamma}$  is shown in Figure 5.

Figure 4. (a) Percolation lattice with random connections; there is a path of black sites between the top and bottom plates, and (b)  $p_2$  versus  $p_1$  for  $1 \times 1$ ,  $2 \times 2$ ,  $6 \times 6$ ,  $24 \times 24$ ,  $120 \times 120$ , and infinite-size lattices

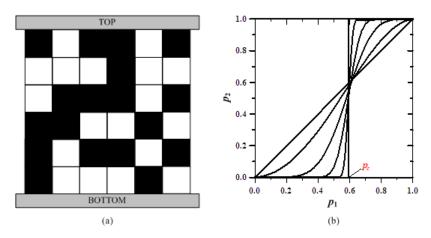
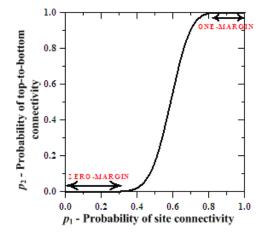


Figure 5. Non-linearity through percolation in random media



#### **Definitions**

Throughout the paper, we use the concept of defect *probability* and defect *rate* interchangeably. We assume that the lattice is large enough for this to hold true.

Definition 1. We define the one margin and zero margin to be the ranges of p1 for which we interpret p2 as unequivocally 1 and 0, respectively.

The percolation curve shown in Figure 5 tells us that unless the defect probability exceeds a zero margin (one margin), we achieve robust connectivity: the top and bottom plates remain disconnected (connected) with high probability. Therefore the one margin and zero margin are the indicators of defect tolerance while the lattice's top and bottom plates are connected and disconnected, respectively. In other words, the margins are the maximum defect probabilities (rates) that can be tolerated. For example,

suppose that a network has 5% zero and one margins. This means that the network will successfully tolerate defects unless the defect probability (rate) exceed 5%.

What follows are some standard definitions from the field of logic synthesis. We will use these terms in the next sections.

Definition 2. Consider k independent Boolean variables,  $x_{\nu}x_{\nu},...,x_{\nu}$ . Boolean literals are Boolean variables and their complements, i.e.,  $x_1, \overline{x}_1, x_2, \overline{x}_2, ..., x_k, \overline{x}_k$ .

Definition 3. A product (P) is an AND of literals, e.g.,  $P = x_1 \overline{x}_3 x_4$ . A sum-of-products (SOP) expression corresponds to an OR of products.

Definition 4. A prime implicant (PI) of a Boolean function f is a product that implies f such that removing any literal from the product results in a new product that does not imply f.

Definition 5. An irredundant sum-of-products (ISOP) expression is an SOP expression, where each product is a PI, and no PI can be deleted without changing the Boolean function f represented by the expression. Among the SOPs for f, one with the minimum number of products is a minimum sum-of-products (MSOP) expression.

Definition 6. fand gare dual Boolean functions if

$$f(x_1, x_2, ..., x_k) = \overline{g}(\overline{x}_1, \overline{x}_2, ..., \overline{x}_k).$$

A dual of a function also can be obtained by interchanging AND and OR operations as well as the constants 0 and 1. For example, if  $f = x_1 x_2 + \overline{x}_1 x_3$  $f^{D} = (x_1 + x_2) + (\overline{x}_1 + x_3)$ . Another trivial example is that for f = 1 the dual is  $f^D = 0$ .

#### APPLICABLE TECHNOLOGIES

The main contributions of this paper are conceptual. Our circuit and defect models are simple and broadly applicable to different types of emerging technologies. A schematic for the realization of our circuit model is shown in Figure 6. Each site of the lattice is a four-terminal switch, controlled by an input voltage. When a high (logic 1) or low (logic 0) voltage is applied, the switch is ON or OFF, respectively. The output of the circuit depends upon the topto-bottom connectivity across the lattice. If the top and bottom plates are connected, then the lattice allows signals to flow; accordingly, the output is logic 1. Otherwise the output is logic 0. One can sense the output with a resistor connected to the bottom plate while a high voltage applied to the top plate. Below, we discuss two potential technologies that fit this circuit model.

In their seminal work, Yi Cui and Charles Lieber investigated crossbar structures for different types of nanowires including *n*-type and p-type nanowires (Cui & Lieber, 2001). They achieved the different types of junctions by crossing different types of nanowires.

By crossing an *n*-type nanowire and a p-type nanowire, they achieved a diode-like junction. By crossing two *n*-types or two *p*-types, they achieved a resistor-like junction (with a very low resistance value). They showed that the connectivity of nanowires can be controlled by an insulated input voltage V-in. A high V-in makes the p-type nanowires conductive and the n-type nanowires resistive; a low V-in makes the p-type nanowires resistive and the n-type nanowires conductive. So they showed that, based on a controlling voltage, nanowires can behave either like short circuits or like open circuits.

Cui and Lieber implemented a four-terminal device with crossed *n*-and *p*-type nanowires, illustrated in Figure 7(a). The device works as follows. When a high V-in is applied, a p-type nanowire (green) behaves like a short circuit, so the N and S terminals are connected, and an *n*-type nanowire (red) behaves like an open circuit, so the W and E terminals are disconnected. When a low V-in is applied, a p-type nanowire behaves like an open circuit, so the N and S terminals are disconnected, and an n-type nanowire behaves like a short circuit, so the W and E terminals are connected.

One could easily implement a four-terminal switch with similar techniques, as illus-

Figure 6. 3D realization of our circuit model with the inputs and the output

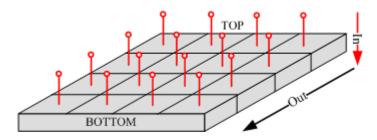
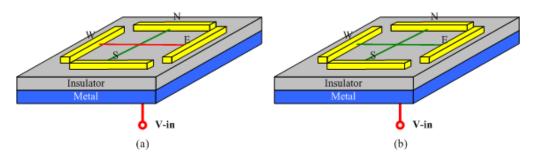


Figure 7. Nanowire four-terminal devices



trated in Figure 7(b). Here the switch has crossed p-type nanowires. When a high V-in is applied, the nanowires behave like short circuits. Also a resistor-like junction is formed between them, meaning that the nanowires are connected through a low-valued resistor. Thus, all the four-terminals are connected; the switch is ON. When a low V-in is applied, the nanowires behave like open circuits. Thus, all the four-terminals are disconnected; the switch is OFF. The result is a four-terminal switch that corresponds to our model.

Nanowire switches, of course, would be assembled in large arrays. Indeed, the impetus for nanowire-based technology is the potential density, scalability and manufacturability (Huang et al., 2001; Luo et al., 2002; DeHon, 2005). Consider a *p*-type nanowire array, where each crosspoint is controlled by an input voltage. From the discussion above, we know that each such crosspoint behaves like a four-terminal switch. Accordingly, the nanowire crossbar array can be modelled as a lattice of four-terminal switches as illustrated in Figure 8. Here the

black and white sites represent crosspoints that are ON and OFF, respectively.

Many other novel and emerging technologies fit the general model of four-terminal switches. For instance, researchers are investigating *spin waves* (Eshaghian-Wilner, Khitun, Navab, & Wang, 2006). Unlike conventional circuitry such as CMOS that transmits signals electrically, spin-wave technology transmits signals as propagating disturbances in the ordering of magnetic materials. Potentially, spin-wave based logic circuits could compute with significantly less power than conventional CMOS circuitry.

Spin wave switches are four-terminal devices, as illustrated in Figure 9. They have two states ON and OFF, controlled by an input voltage V-in. In the ON state, the switch transmits all spin waves; all the four-terminals are connected. In the OFF state the switch reflects any incoming spin waves; all the four-terminals are disconnected. Spin-wave switches, like nanowire switches, are also configured in crossbar networks (Khitun et al., 2008).

Figure 8. Nanowire crossbar array with random connections and its lattice representation

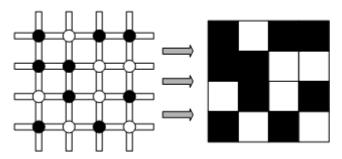
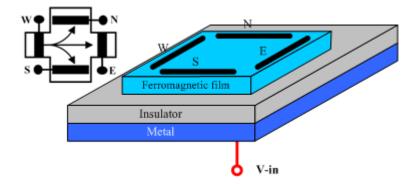


Figure 9. Spin-wave switch



# LOGIC SYNTHESIS THROUGH PERCOLATION

We implement Boolean functions with a single lattice of four-terminal switches, as illustrated in Figure 10 (Altun, Riedel, & Neuhauser, 2009). There are  $R \times C$  regions  $r_{11},...,r_{RC}$  in the lattice. Each region has  $N \times M$  four-terminal switches. Weassign Booleanliterals  $x_1, \overline{x}_1, x_2, \overline{x}_2, ..., x_k, \overline{x}_k$ to regions as controlling inputs. If an input literal is logic 1 then all switches in the corresponding region are ideally ON; if the literal is logic 0 then all switches in the corresponding region are ideally OFF. This is illustrated in Figure 11.

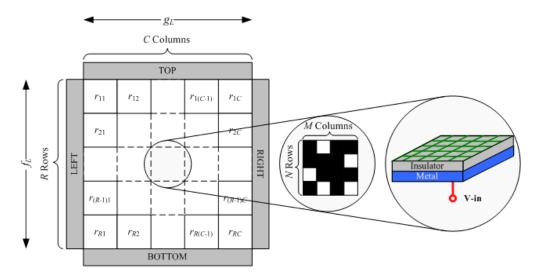
In our synthesis method, a Boolean function is implemented by a lattice according to the connectivity between the top and bottom plates. For the purpose of elucidating our method, we will also discuss connectivity between the left and right plates. Call the Boolean functions

corresponding to the top-to-bottom and left-toright plate connectivities fL and gL, respectively. (However, note that our design method does not aim to implement separate top-tobottom and left-to-right functions. As we explain below,  $f_i$  and  $g_i$  are related.)

As shown in Figure 11, each Boolean function evaluates to 1 if there exists a path between corresponding plates and evaluates to 0 otherwise. Thus, the Boolean functions  $f_{ij}$ and  $g_i$  can be computed as the OR of all topto-bottom and left-to-right paths, respectively. Since each path corresponds to the AND of inputs, the paths taken together correspond to the OR of these AND terms, so implement a sum-of-products expression.

Note that the values of N and M do not affect the Boolean functionality between plates; they determine the defect tolerance capability of the lattice. Therefore, for simplicity, let's set N=1 and M=1 while computing the Boolean

Figure 10. Boolean computation in a lattice, i.e., each region has  $N \times M$  four-terminal switches. Each region can be realized by an  $N \times M$  nanowire crossbar array with a controlling voltage V-in



functions  $f_L$  and  $g_L$ . In this way, there are fewer paths to count between the corresponding plates. Consider the lattice shown in Figure 12(a): here there are 6 regions each of which is controlled by a Boolean literal. With N = and M = 1, there are 3 top-to-bottom paths and 4 left-to-right paths, as shown in Figure 12(b). Here  $f_L$  is the

OR of the 3 products  $x_1\overline{x}_3, \overline{x}_1x_2, x_3x_4$  and  $g_L$  is the OR of the 4 products  $x_1x_2x_3, x_1\overline{x}_1x_2x_4, \overline{x}_1x_2x_3, x_1\overline{x}_1x_3x_4$ . As a result,  $f_L = x_1x_3 + \overline{x}_1x_2 + x_3x_4$  and  $g_L = \overline{x}_1x_3x_4 + x_2x_3$ . In the following section, we study the robustness of the lattice computation. We inves-

Figure 11. Relation between Boolean functionality and paths;  $f_L = 1$  and  $g_L = 0$ . (a) Each of the 16 regions is assigned logic 0 or 1; R = 4 and C = 4, and (b) Each region has 9 switches; N = 3 and M = 3

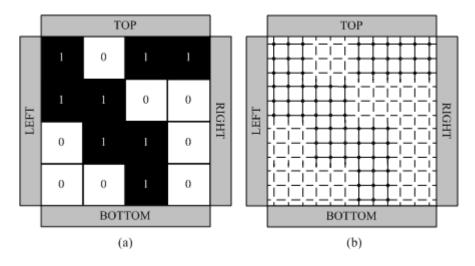
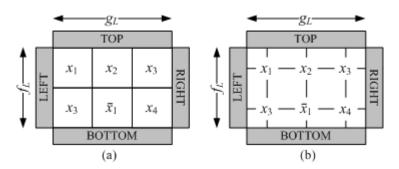


Figure 12. (a) A lattice with assigned inputs to 6 regions, and (b) Switch-based representation of the lattice; N = 1 and M = 1



tigate the computation, implemented in terms of connectivity across the lattice, in the presence of defects.

#### Robustness

An important consideration in synthesis is the quality of the margins, defined in Definition 1. Suppose that the one and zero margins are the ranges of values for  $p_1$  for which  $p_2$  is always above  $(1 - \in)$  and below  $\in$ , respectively, where ∈ is a very small number. For what follows, we will use a value  $\in =0.001$ . The margins correlate with the degree of defect tolerance. For instance a 10% one margin means that a defect rate of up to 10% can be tolerated while the corresponding Boolean function evaluates to 1. In other words, although each switch is defective with probability 0.1, the circuit still evaluates to 1 with high probability  $(p_2 > 0.999)$ . The higher the margins, the higher the defect tolerance that we achieve.

Different assignments of input variables to the regions of the lattice affect the margins. Consider a 4-input  $2 \times 2$  lattice shown in Figure 13(a). Suppose that N = 8 and M = 8 for this lattice. Figure 13(b) shows Boolean functionalities and margins for different input assignments. Since the lattice has 4 input variables  $x_1, x_2, x_3, x_4$  there should be 16 different input assignments. However, there are only 7 rows in the table. Some input assignments produce the same result due to symmetries in the lattice: flipping the lattice vertically or horizontally gives us two different input assignments that are identical in terms of margins as well as the Boolean functionality. Note that each margin value in the table corresponds to either a one margin (if the corresponding Boolean function is 1) or a zero margin (if the corresponding Boolean function is 0). We define the worstcase one and zero margins to be the minimum one and zero margins of all input assignments. For example, the table shown in Figure 13(b) states that  $f_t$  has a 14% worst-case one margin and a 0% worst-case zero margin.

The row highlighted in grey has very low margins – indeed, these are nearly zero – so the circuit is likely to produce erroneous values for this input combination. Let's examine why. Assignments that evaluate to 0 but have diagonally adjacent assignments of blocks of 1's could be problematic because there is a chance that a weak connection will form through stray, random connections across the diagonal. This is illustrated in Figure 14. In this example,  $f_i$ and  $g_i$  both evaluate to 0; however the top-tobottom and left-to-right connectivities evaluate to 1 if a defect occurs around the diagonal 1's. In effect, such defective switches are "shorting" the connection. So in this case  $f_L$  and  $g_L$  both evaluate to 1, incorrectly.

Note that diagonal paths are only problematic when the corresponding Boolean function evaluates to 0 because the diagonal paths can only cause  $0 \rightarrow 1$  errors. If the Boolean function evaluates to 1, these diagonal paths do not cause

Figure 13. (a) A lattice with assigned inputs; R = 2 and C = 2, and (b) Possible 0/1 assignments to the inputs (up to symmetries) and corresponding margins for the lattice (N = 8, M = 8)

	TOP				
LEFT	$x_1$	$x_2$	RIGHT		
	<i>X</i> <sub>3</sub>	<i>X</i> <sub>4</sub>	THE		
BOTTOM					
(a)					

$x_1$	$x_2$	$x_3$	$x_4$	$f_L$	Margin	$g_L$	Margin
0	0	0	0	0	40%	0	40%
0	0	0	1	0	25%	0	25%
0	1	0	1	1	14%	0	23%
0	0	1	1	0	23%	1	14%
0	1	1	0	0	0%	0	0%
0	1	1	1	1	14%	1	14%
1	1	1	1	1	25%	1	25%
(b)							

such an error; at best they strengthen the connection between plates. This is illustrated in Figure 15. In the figure, there are both top-tobottom and left-to-right diagonal paths shown with red lines. However, only the top-to-bottom diagonal path is destructive because only  $f_i$ evaluates to  $0 (g_L = 1)$ .

Definition of Robustness: We call a lattice robust if there is no input assignment for which the top-to-bottom function evaluates to 0 that contains diagonally adjacent 1's.

The following theorem tells us the necessary and sufficient condition for robustness.

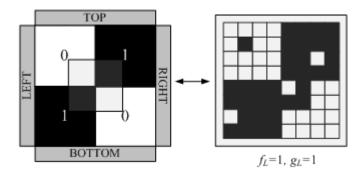
Theorem 1. A lattice is robust if the top-tobottom and left-to-right functions  $f_i$  and  $g_i$  are dual functions:  $f_L(x_1, x_2, ..., x_k) =$  $\overline{g}_{I}(\overline{x}_{1},\overline{x}_{2},...,\overline{x}_{k}).$ 

(See Definition 6 for the meaning of dual.)

Proof. In the proof, we consider two cases, namely  $f_L = 1$  and  $f_L = 0$ .

Case 1. If  $f_t(x_1, x_2, ..., x_k) = 1$ , there must be a path of 1's between top and bottom. If we complement all the inputs  $(1 \rightarrow 0, 0 \rightarrow 1)$ , these connected 1's become 0's and vertically separate the lattice into two parts. Therefore no path of 1's exists between the left and right plates, i.e.,  $g_L g_L(\overline{x}_1, \overline{x}_2, ..., \overline{x}_k)$ . As a result,  $\overline{g}_L(\overline{x}_1, \overline{x}_2, ..., \overline{x}_k) = f_L(x_1, x_2, ..., x_k) = 1$ 

Figure 14. An input assignment with a low zero margin



TOP

Figure 15. An input assignment with top-to-bottom and left-to-right diagonal paths

Case 2. If  $f_i(x_1,x_2,...,x_k) = 0$  and there are no diagonally connected top-to-bottom paths, there must be a path of 0's between left and right. If we complement all the inputs, these connected 0's become 1's, i.e.,  $\begin{array}{l} g_{L}(\overline{x}_{1},\overline{x}_{2},...,\overline{x}_{k})=1 \text{. As a result,} \\ \overline{g}_{L}(\overline{x}_{1},\overline{x}_{2},...,\overline{x}_{k})=f_{L}(x_{1},x_{2},...,x_{k})=0 \end{array}$ 

Figure 16 illustrates the two cases. Taken together the two cases prove that for robust computation,  $f_L$  and  $g_L$  must be dual functions. For both cases it is trivial that we can do the same reasoning in an inverse way: if  $f_i$  and  $g_i$ are dual functions then every input assignment is robust.

Example 1. Consider the lattices shown in Figure 17. For both lattices, R = 2 and C=2. Let's analyze the robustness of these two lattices using Theorem 1.

Example (a): The Boolean functions implemented by the lattice are  $f_1 = x_1x_3 +$  $\mathbf{x}_2 \mathbf{x}_4$  and  $\mathbf{g}_L = \mathbf{x}_1 \mathbf{x}_2 + \mathbf{x}_3 \mathbf{x}_4$ . Since  $f_L^D = (\mathbf{x}_1 + \mathbf{x}_3)(\mathbf{x}_2 + \mathbf{x}_4) = \mathbf{x}_1 \mathbf{x}_2 + \mathbf{x}_1 \mathbf{x}_4 + \mathbf{x}_2 \mathbf{x}_3$  $+ x_3 x_4 = g_L$ , so  $f_L$  and  $g_L$  are not dual functions. Theorem 1 tells us that if f, and g<sub>1</sub> are not dual then there exists an non-robust input assignment. We can easily identify it:  $x_1 = 1, x_2 = 0, x_3$  $=0,x_{4}=1.$ 

Example (b): The Boolean functions implemented by the lattice are  $f_L = x_1 x_3 + \overline{x}_1 x_2$  and  $g_{L} = x_1 x_2 + \overline{x}_1 x_3.$ Since  $f_L^D = (x_1 + x_3) + (\overline{x}_1 + x_2) =$  $x_1x_2 + \overline{x}_1x_3 = g_1$ , so  $f_1$  and  $g_1$  are dual L functions. Theorem 1 tells us that if fL and gL are dual then every assignment is robust. One can easily see that none of the input assignments cause

Figure 16. Illustration of Theorem 1

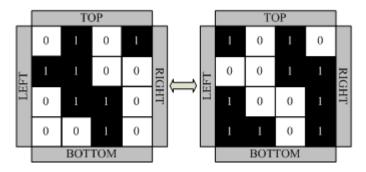
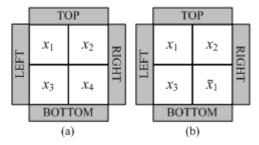


Figure 17. (a) An example of non-robust computation and (b) An example of robust computation



diagonal 1's while the corresponding function evaluates to 0.

We conclude that, in order to achieve robust computation, we must design lattices that have dual top-to-bottom and left-to-right Boolean functions.

# **Logic Optimization Problem**

This gives rise to an interesting problem in logic optimization: given a target function fT in SOP form, how should we assign the input literals such that  $f_L = f_T$  and  $g_L = f_T^D$ ? In other words, how should we assign literals so that the lattice implements the target function between the top and bottom plates, and implements the dual of the function between the left and right plates? As described in the previous section, having dual functions ensures robustness.

While maximizing the margins, we also need to consider the area of the lattice; this can be measured by the total number of switches  $R \times$  $C \times N \times M$  in the lattice. Here  $R \times C$  and  $N \times M$ represent the number of regions and the number of switches for each region, respectively.

We suggest a four-step algorithm for optimizing the lattice area while meeting prescribed worst-case margins for a given target function  $f_{T}$ . Algorithm:

- Begin with the target function fT and its dual  $f_T^D$  both in MSOP form.
- Find a lattice with the smallest number of regions that satisfies the conditions:  $f_I = f_T$ and  $g_L = f_T^D$ . This determines  $R \times C$ .

- Dependent on the defect rates of the technology, determine the required worst-case one and zero margin values.
- Determine the number of switches required in each region in order to meet the prescribed margins. This determines  $N \times M$ .

The first step is straightforward. The dual of the target function can be computed from Definition 6. Exact methods such as Quine-McCluskey or heuristic methods such as Espresso can be used to obtain functions in MSOP form (Mc-Cluskey, 1986; Brayton, McMullen, Hachtel, & Sangiovanni-Vincentelli, 1984).

For the second step of the algorithm, we point the reader to our prior work. In Altun and Riedel (2010, in press), we addressed the problem of assigning literals to switches in a lattice in order to implement a given target Boolean function. The goal was to minimize the number of regions. We presented an efficient algorithm that produces lattices with a size that grows linearly with the number of products of the target Boolean function. Suppose that  $f_T$  and  $f_T^D$  in MSOP form have A and B product terms, respectively. Our algorithm produces lattices with  $B \times A$  regions (R = B and C = A) for which  $f_L = f_T$  and  $g_L = f_T^D$  (Altun & Riedel, in press). For the third step, we assume that the de-

fect rates of the switches are known or can be estimated. Recall that we consider two types of defects: those that result in switches being OFF while they are supposed to be ON (call these "ON-to-OFF" defects), and defects that result in switches being ON while they are

N	М	One Margin	Zero Margin	Sum of Margins
1	•	<b>1</b>	1	1
•	1	1	1	1

Figure 18. Relationship between margins, and N and M

supposed to be OFF (call these "OFF-to-ON" defects). We allow for different rates for both types of defects. Based upon the ON-to-OFF and OFF-to-ON defect rates, we establish the worst-case one and zero margins, respectively.

For the fourth step, we need to determine N and M such that the lattice meets the prescribed margins. Figure 18 shows the general relationship between margins and N and M. It suggests how we should select values of N and M. For instance, suppose that we require a 20% one margin and a 5% zero margin. Figure 18 tells us that we need to select a larger value of M than that of N. Also, from the figure, we observe that regardless of whether we increase N or M, the sum of the margins always increases. This is due to the percolation phenomenon: the larger the lattice, the steeper the non-linearity curve. Based upon these considerations, we use a simple greedy technique to set the required values of N and M. The method tries worst-case margins for different values of N and M until the prescribed margins are met.

We elucidate our algorithm with the following examples. For all of the examples, we use 10% worst-case one and zero margins.

Example 2. Suppose that we are given the following target function fT in MSOP form:

$$f_{\mathrm{T}} = \chi_{1} \chi_{2}$$

First, we compute its dual  $f_T^D$  in MSOP form:

$$f_T^D = x_1 + x_2.$$

The number of products in  $f_T$  and  $f_T^D f^D$  are  $f_T^D = x_1 x_2 x_5 + x_1 x_3 x_4 + x_2 x_3 x_4$ 1 and 2, respectively, i.e., A = 1 and = 2.

Then, we construct a lattice such that  $f_L =$  $f_T = x_I x_2$  and  $gL = f_T^D = x_I + x_2$ . The lattice is illustrated in Figure 19. Note that R = B = 2 and C = A = 1. Finally, we find that N = 4 and M = 6in order to satisfy 10% worst-case one and zero margins. As a result, the lattice area =  $R \times C \times C$  $N \times M = 2 \times 1 \times 4 \times 6 = 48$ .

Example 3. Suppose that we are given the following target function fT in MSOP form:

$$f_{\scriptscriptstyle T} = x_{\scriptscriptstyle 1} \overline{x}_{\scriptscriptstyle 2} + \overline{x}_{\scriptscriptstyle 1} x_{\scriptscriptstyle 2}.$$

First, we compute its dual  $f_T^D$  in MSOP form:

$$f_T^D = x_1 x_2 + \overline{x}_1 \overline{x}_2.$$

We have that A = 2 and B = 2. Then, we construct a lattice such that  $f_L = f_T$  and  $g_L = f_T$  $f_{\tau}^{D}$ . The lattice is illustrated in Figure 20. Note that R = B = 2 and C = A = 2. Finally, we find that N = 4 and M = 6 in order to satisfy 10% worst-case one and zero margins. As a result, the lattice area =  $R \times C \times N \times M = 2 \times 2 \times 4 \times 1$ 6 = 96.

Example 4. Suppose that we are given the following target function fT in MSOP form:

$$\begin{split} f_T &= x_1 \overline{x}_2 x_3 + x_1 \overline{x}_4 + x_2 x_2 \overline{x}_4 \\ &+ x_2 x_4 x_5 + x_3 x_5 \,. \end{split}$$

First, we compute its dual  $f_T^D$  in MSOP

$$f_T^D = x_1 x_2 x_5 + x_1 x_3 x_4 + x_2 x_3 x_4 + x_2 x_3 \overline{x}_4 + \overline{x}_2 \overline{x}_4 x_5.$$

Figure 19. A lattice that implements  $f_L = x_1 x_2$  and  $g_L = x_1 + x_2$ 

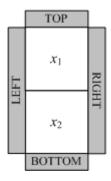


Figure 20. A lattice that implements  $f_L = x_1 \overline{x}_2 + \overline{x}_1 x_2$  and  $g_L = x_1 x_2 + \overline{x}_1 \overline{x}_2$ .

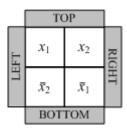


Figure 21. A lattice that implements  $f_L = x_1\overline{x}_2x_3 + x_1\overline{x}_4 + x_2x_2\overline{x}_4 + x_2x_4x_5 + x_3x_5$  and  $g_L = x_1x_2x_5 + x_1x_3x_4 + x_2x_3\overline{x}_4 + \overline{x}_2\overline{x}_4x_5$ .

	TOP							
LEFT	$x_1$	$x_1$	<i>x</i> <sub>2</sub>	$x_2$	X5			
	$x_1$	$x_1$	<i>x</i> <sub>3</sub>	<i>X</i> <sub>4</sub>	<i>x</i> <sub>3</sub>	RIGHT		
	<i>X</i> <sub>3</sub>	$\overline{X}_4$	<i>x</i> <sub>2</sub>	<i>x</i> <sub>2</sub>	Х3	THE		
	$\overline{x}_2$	$\overline{x}_4$	$\overline{x}_4$	<i>X</i> <sub>5</sub>	<i>X</i> <sub>5</sub>			
	BOTTOM							

We have that A = 5 and B = 4. Then, we construct a lattice such that  $f_L = f_T$  and  $g_L =$  $f_T^D$ . The lattice is illustrated in Figure 21. Note that R = B = 4 and C = A = 5. Finally, we find that N = 4 and M = 5 in order to satisfy 10% worst-case one and zero margins. As a result, the lattice area =  $R \times C \times N \times M = 4 \times 5 \times 4 \times 10^{-5}$ 5 = 400.

We implement the target functions with specified margins. Note that because of the lattice duality, the one and zero margins of target functions become the zero and one margins of their duals, respectively.

# EXPERIMENTAL RESULTS

We report synthesis results for some common benchmark circuits (McElvain, 1993). We consider each output of a benchmark circuit as a separate target Boolean function. Figure 22 lists the required lattice areas for the target functions meeting 10% worst-case one and zero margins. Recall that the lattice area is defined as the number of switches in the lattice. It can be calculated as  $R \times C \times N \times M$  where  $R \times C$ and  $N \times M$  represent the number of regions and the number of switches for each region, respectively.

In order to obtain the lattice areas, we follow the steps of the proposed algorithm in the above section. We first obtain values for A and B, the number of products in the target functions and their duals, respectively. Our algorithm sets R = A and C = B, so produces lattices with  $B \times$ A regions. We calculate values of N and M that satisfy the prescribed 10% worst-case margins.

Figure 22 reports the lattice areas, calculated as  $A \times B \times N \times M$ . Examining the numbers in the table, we see that number of switches needed per region,  $N \times M$ , is negatively correlated with the number of regions,  $A \times B$ . That is to say, Boolean functions with more products (larger  $A \times B$  values) need smaller regions (smaller N × M values) to meet prescribed margins. This indicates a positive scaling trend: the lattice size grows more slowly than the function size. This key behavior is due to the percolation phenomena.

# DISCUSSION

The two-terminal switch model is fundamental and ubiquitous in electrical engineering (Bryant, 1987). Either implicitly or explicitly, nearly all logic synthesis methods target circuits built from two-terminal switches, i.e., transistors. And yet, with the advent of novel nanoscale technologies, synthesis methods targeting lattices of multi-terminal switches are apropos. Our model consists of a regular lattice of multi-terminal switches, each controlled by a Boolean literal. This model is conceptually general and applicable to a range of emerging technologies, including nanowire crossbar arrays (Cui & Lieber, 2001) and magnetic switch-based structures (Khitun et al., 2008). We are investigating its applicability to DNA nanofabrics (Pistol, Lebeck, & Dwyer, 2006; Rothemund, 2006). In this paper, we focused on four-terminal switches. In future work, we will the extend the results paper to lattices of eight-terminal switches, and then to 2k-terminal switches, for arbitrary k.

Particularly with self-assembly, nanoscale lattices are often characterized by high defect rates. Significantly, unlike many other strategies for defect tolerance, our method does not require defect identification followed by reconfiguration. Our method provides a priori tolerance to defects of any kind, both permanent and transient, provided that such defects occur probabilistically and independently. Indeed, percolation depends on a random distribution of defects. If the defect probabilities are correlated across regions, then the steepness of the percolation curve decreases; as a result, the defect tolerance diminishes. In future work, we will study this tradeoff mathematically and develop synthesis strategies to cope with correlated probabilities in defects.

Circuit	A	B	Number of	N	M	Lattice
			regions			area
alu1	3	2	6	5	6	180
alu1	2	3	6	4	6	144
alu1	1	3	3	4	6	72
clpl	4	4	16	4	5	320
clpl	3	3	9	4	5	180
clpl	2	2	4	4	6	96
clpl	6	6	36	4	5	720
clpl	5	5	25	4	5	500
newtag	8	4	32	5	5	800
dc1	4	4	16	4	5	320
dc1	2	3	6	4	6	144
dc1	4	4	16	4	5	320
dc1	4	5	20	4	6	480
dc1	3	3	9	4	5	180
misex1	2	5	10	4	7	280
misex1	5	7	35	4	6	840
misex1	5	8	40	4	6	960
misex1	4	7	28	4	6	672
misex1	5	5	25	4	5	500
misex1	6	7	42	4	5	840
misex1	5	7	35	4	6	840
b12	4	6	24	4	6	576
b12	7	5	35	5	5	875
b12	7	6	42	5	5	1050
b12	4	2	8	5	6	240
b12	4	2	8	5	6	240
b12	5	1	5	6	5	150
b12	9	6	54	5	5	1350
b12	6	4	24	5	5	600
b12	7	2	14	6	5	420
newbyte	1	5	5	4	7	140
c17	3	3	9	4	5	180
c17	4	2	8	5	6	240
rd53	5	10	50	4	6	1200
rd53	10	10	100	4	5	2000
rd53	16	16	256	3	5	3840

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